

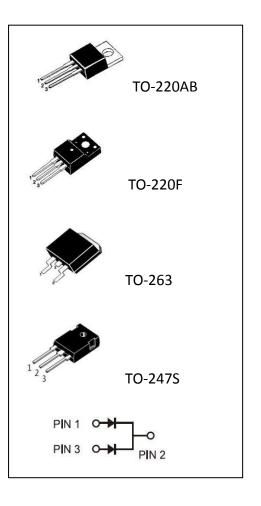
S40C45C/F/B/W-S40C60C/F/B/W

Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, charger, DC/DC converters and polarity protection diodes.

Features

- Low Forward Voltage.
- Low Switching noise.
- High Current Capacity.
- Guarantee Reverse Avalanche.
- Guard-Ring for Stress Protection.
- Low Power Loss & High efficiency.
- 150°C Operating Junction Temperature.
- Low Stored Charge Majority Carrier Conduction.
- Flammability Classification 94V-O.
- Lead free in compliance with EU RoHS 2011/65/EU directive.



Maximum Ratings (Per Leg) at Ta=25°C unless otherwise specified

Characteristics		Symbol	S40C4	5	S40C60	Unit
Maximum Repetitive Peak Reverse Voltage Working Peak Reverse Voltage Maximum DC Blocking Voltage		Vrrm Vrwm Vr	45		60	V
RMS Reverse Voltage		VR(RMS)	32		42	V
Maximum Average Forward Rectified Current		lo	40		А	
Peak Forward Surge Current,8.3 ms Single Half Sine-wave		IFSM	350		А	
Maximum Instantaneous Forward Voltage (per diode) (Note1) (IF =5.0 Amp TC = 25° C)		V _F	0.55		0.68	V
Maximum Instantaneous Reverse	TA=25°C	I _R	0.3		mA	
Current	TA=125°C		30		mA	
Operating and Storage Jemperature Temperature Range		TJ, Tstg	-55 to +150		°C	
Typical Thermal Resistance(Note 2)		Rθj-c	3		°C/W	

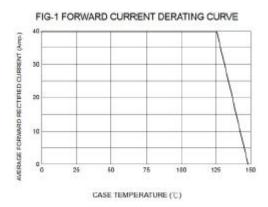
Note1: Pulse test: 300 µs pulse width, 2 % duty cycle.

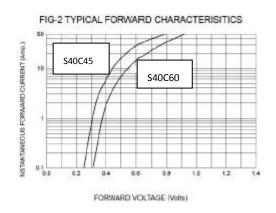
2: Thermal resistance junction to case.

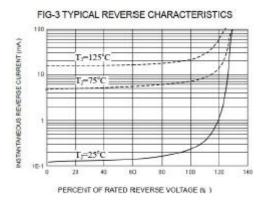


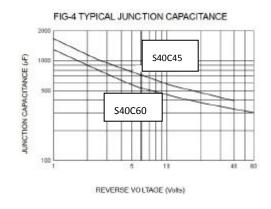
\$40C45C/F/B/W-\$40C60C/F/B/W

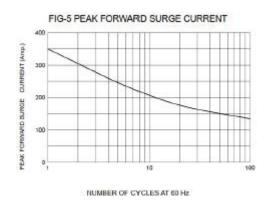
RATING AND CHARACTERTIC CURVES







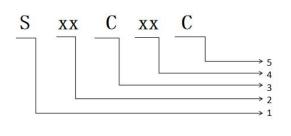




\$40C45C/F/B/W-\$40C60C/F/B/W

Marking on the body

Diode tube naming convention



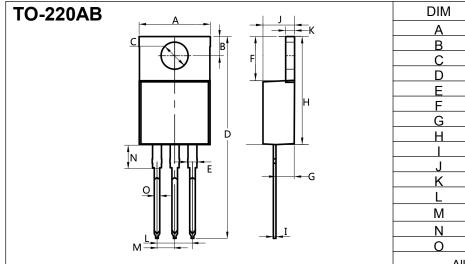
- 1: **S**: Schottky **F**: Recovery
- 2: Rated current(A)
- 3: C: GPP Recovery/Schottky

F: fast **U**: Super fast **H**: Super fast **HP**: Super fast, PFC diode

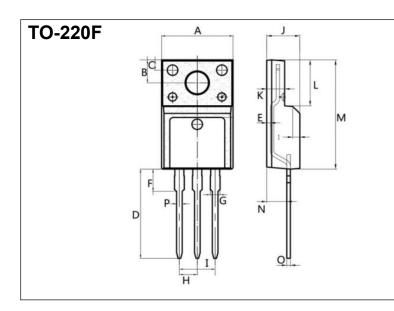
- 4: Rated voltage(V)
- 5: Package

C: TO-220AB F: TO-220F A: TO-220AC P: TO-220FAC B: TO-263 W: TO-3P/TO-247S

Package Outline Dimensions millimeters

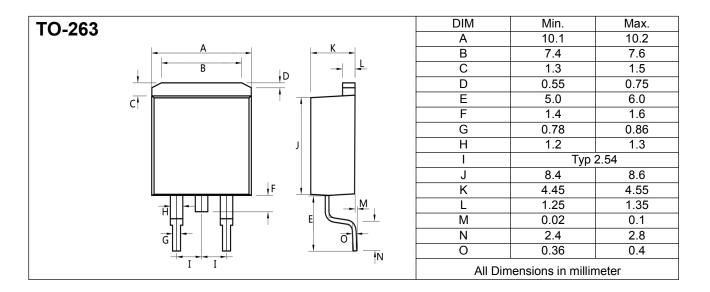


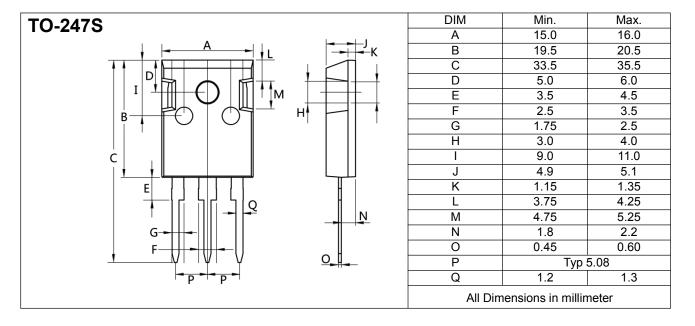
DIM	Min.	Max.			
Α	10.15	10.35			
В	2.65	3.0			
С	3.7	3.9			
D	28.5	29			
E	1.3	1.45			
F	6.35	6.55			
G	2.9	3.3			
H	15.0	16.			
I	0.38	0.4			
J	4.45	4.55			
K	1.25	1.35			
L	Typ 5.08				
M	Typ 2.54				
N	3.1	3.3			
0	0.76	0.84			
All Dimensions in millimeter					



DIM	Mın.	Max.		
Α	9.9	10.3		
В	2.9	3.5		
С	1.15	1.45		
D	12.75	13.45		
E	0.55	0.75		
F	3.1	3.5		
G	1.25	1.45		
Н	Typ 2.54			
I	Typ 5.08			
J	4.55	4.75		
K	2.4	2.7		
L	6.35	6.75		
M	15.0	16.0		
N	2.75	3.15		
0	0.45	0.60		
Р	0.7	0.9		
All Dimensions in millimeter				

S40C45C/F/B/W-S40C60C/F/B/W





Statement:

- We reserve the right to change the manual without prior notice! Customers should obtain the latest version of the information before placing an order, and verify that the relevant information is complete and up-to-date.
- ◆ Any semiconductor product has the possibility of failure or failure under specific conditions. The buyer has the responsibility to comply with safety standards and take safety measures when using Silan product for system design and complete machine manufacturing, so as to avoid the occurrence of personal injury or property loss caused by potential failure risk!
- Product promotion will never end, our company will wholeheartedly provide customers with more excellent products!